

LMV331 Single, LMV393 Dual, LMV339 Quad General-purpose Low-voltage Comparators

1 Features

- 2.7-V and 5-V Performance
- Low Supply Current
 - LMV331 130 μA Typ
 - LMV393 210 μA Typ
 - LMV339 410 μA Typ
- Input Common-Mode Voltage Range Includes Ground
- Low Output Saturation Voltage 200 mV Typical
- Open-Collector Output for Maximum Flexibility

2 Applications

- Hysteresis Comparators
- Oscillators
- Window Comparators
- Industrial Equipment
- Test and Measurement

3 Description

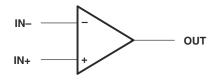
The LMV393 and LMV339 devices are low-voltage (2.7 V to 5.5 V) versions of the dual and quad comparators, LM393 and LM339, which operate from 5 V to 30 V. The LMV331 is the single-comparator version.

The LMV331, LMV339, and LMV393 are the most cost-effective solutions for applications where low-voltage operation, low power, and space saving are the primary specifications in circuit design for portable consumer products. These devices offer specifications that meet or exceed the familiar LM339 and LM393 devices at a fraction of the supply current.

Device Information

| PART NUMBER | PACKAGE (PIN) ⁽¹⁾ | BODY SIZE (NOM) | | | | | | |
|-------------|------------------------------|-------------------|--|--|--|--|--|--|
| LMV339 | SOIC (14) | 8.65 mm x 3.90 mm | | | | | | |
| LMV393 | SOIC (8) | 4.90 mm x 3.90 mm | | | | | | |
| LMV331 | SC70 (5) | 2.00 mm x 1.25 mm | | | | | | |

(1) For all available packages, see the orderable addendum at the end of the datasheet.



Simplified Schematic



Table of Contents

| 1 Features 2 Applications | |
|--|----------------|
| 3 Description | |
| 4 Revision History | |
| 5 Pin Configuration and Functions | 3 |
| 6 Specifications | 4 |
| 6.1 Absolute Maximum Ratings | 4 |
| 6.2 ESD Ratings | 4 |
| 6.3 Recommended Operating Conditions | |
| 6.4 Thermal Information | 4 |
| 6.5 Electrical Characteristics, V _{CC+} = 2.7 V | <mark>5</mark> |
| 6.6 Electrical Characteristics, V _{CC+} = 5 V | 6 |
| 6.7 Switching Characteristics, V _{CC+} = 2.7 V | 6 |
| 6.8 Switching Characteristics, V _{CC+} = 5 V | 7 |
| 6.9 Typical Characteristics | 7 |
| 7 Detailed Description | 9 |
| 7.1 Overview | |

| 7.2 Functional Block Diagram | 9 |
|---|----|
| 7.3 Feature Description. | |
| 7.4 Device Functional Modes | |
| 8 Application and Implementation | |
| 8.1 Application Information | 10 |
| 8.2 Typical Application | |
| 9 Power Supply Recommendations | |
| 10 Layout | |
| 10.1 Layout Guidelines | |
| 10.2 Layout Example | |
| 11 Device and Documentation Support | |
| 11.1 Related Links | |
| 11.2 Trademarks | |
| 11.3 Electrostatic Discharge Caution | |
| 11.4 Glossary | |
| 12 Mechanical, Packaging, and Orderable | |
| Information | |
| | |

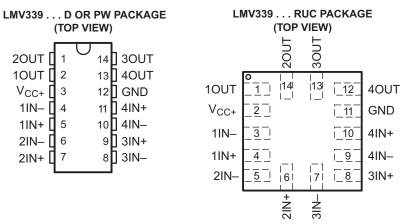
4 Revision History

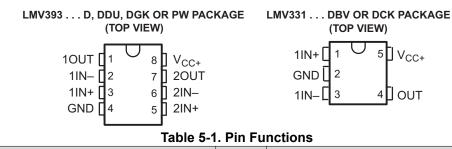
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| С | hanges from Revision T (January 2015) to Revision U (October 2020) | Page |
|---|--|------|
| • | Updated the numbering format for tables, figures and cross-references throughout the document | 1 |
| С | hanges from Revision S (October 2012) to Revision T (January 2015) | Page |
| • | Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Informatable, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Description and Application and Crederable Information section, Power Supply Recommendations section, Layout section, Device and Description and Crederable Information section, Power Supply Recommendations section, Layout section, Device and Description and Crederable Information Section, Power Supply Recommendations section, Layout section, Device and Description and Crederable Information Section, Device and Description Section, Device Acting Section, Devi | |
| • | Documentation Support section, and Mechanical, Packaging, and Orderable Information section Deleted Ordering Information table | |
| С | hanges from Revision R (May 2012) to Revision S (October 2012) | Page |
| • | Updated operating temperature range | 4 |
| С | hanges from Revision N (April 2011) to Revision O (February 2012) | Page |
| • | Changed V ₁ in the Absolute Maximum Ratings from 5.5 V to V_{CC+} | 4 |
| С | hanges from Revision M (November 2005) to Revision N (April 2011) | Page |
| • | Changed document format from Quicksilver to DocZone | 1 |
| • | Added RUC package pin out drawing | 3 |



5 Pin Configuration and Functions





| PIN | | | | | | | |
|---------------|-----------------------------------|--|---|--|--|--|--|
| LMV331 | LMV393 | LMV339 | | TYPE | DESCRIPTION | | |
| DBV or DCK | D, DDU, DGK or PW | D or PW | RUC | | | | |
| 3 | 2, 6 | 4, 6, 8, 10 | 3, 5, 7, 9 | I | Comparator(s) negative input pin(s) | | |
| 1 | 3, 5 | 5, 7, 9, 11 | 4, 6, 8, 10 | I | Comparator(s) positive input pin(s) | | |
| 2 | 4 | 12 | 11 | I | Ground | | |
| 4 | 1, 7 | 2, 1, 14, 13 | 1, 14, 13, 12 | 0 | Comparator(s) output pin(s) | | |
| 5 | 8 | 3 | 2 | I | Supply Pin | | |
| | DBV or DCK 3 1 2 4 | LMV331 LMV393 DBV or DCK D, DDU, DGK or PW 3 2, 6 1 3, 5 2 4 4 1, 7 | LMV331 LMV393 LM DBV or DCK D, DDU, DGK or PW D or PW 3 2, 6 4, 6, 8, 10 1 3, 5 5, 7, 9, 11 2 4 12 4 1, 7 2, 1, 14, 13 | LMV331 LMV393 LMV339 DBV or DCK D, DDU, DGK or PW D or PW RUC 3 2, 6 4, 6, 8, 10 3, 5, 7, 9 1 3, 5 5, 7, 9, 11 4, 6, 8, 10 2 4 12 11 4 1, 7 2, 1, 14, 13 1, 14, 13, 12 | LMV331LMV393LMV399 $TYPE$ DBV or DCKD, DDU, DGK or PWD or PWRUC32, 64, 6, 8, 103, 5, 7, 9113, 55, 7, 9, 114, 6, 8, 101241211141, 72, 1, 14, 131, 14, 13, 12O | | |



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|---|---|-----|------------------|------|
| V _{CC} | Supply voltage ⁽²⁾ | | | 5.5 | V |
| V _{ID} | Differential input voltage ⁽³⁾ | | | ±5.5 | V |
| VI | Input voltage range (either input) | | 0 | V _{CC+} | V |
| | Duration of output short circuit (one amplifier) to $\operatorname{ground}^{(4)}$ | At or below $T_A = 25^{\circ}C$, $V_{CC} \le 5.5 \text{ V}$ | U | Inlimited | |
| TJ | Operating virtual junction temperature | | | 150 | °C |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Section 6.3 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
| | | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ | ±2000 | |
| V _(ESD) | Electrostatic discharge | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾ | ±1000 | V |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

| | | MIN | MAX | UNIT |
|------------------|--|-----|--------------------|------|
| V _{CC} | Supply voltage (single-supply operation) | 2.7 | 5.5 | V |
| V _{OUT} | Output voltage | | $V_{CC^{+}} + 0.3$ | V |
| T _A | Operating free-air temperature | -40 | 125 | °C |

6.4 Thermal Information

| | | | LMV339 | | LMV393 | | | | LMV331 | | |
|-----------------------|--|----|---------|------|--------|-----|-----|-----|--------|-----|------|
| тн | IERMAL METRIC ⁽¹⁾ | D | PW | RUC | D | DDU | DGK | PW | DBV | DCK | UNIT |
| | | | 14 PINS | | | 8 P | INS | | 5 P | INS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 86 | 113 | 216 | 97 | 210 | 172 | 149 | 206 | 252 | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | _ | — | 51.3 | _ | — | _ | _ | _ | _ | |
| R _{θJB} | Junction-to-board thermal resistance | _ | _ | 59.0 | _ | _ | _ | _ | _ | _ | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | _ | _ | 1.2 | _ | _ | _ | _ | _ | _ | |
| Ψ _{JB} | Junction-to-board characterization parameter | _ | _ | 59.0 | _ | _ | _ | _ | _ | _ | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



6.5 Electrical Characteristics, V_{CC+} = 2.7 V

 V_{CC+} = 2.7 V, GND = 0 V, at specified free-air temperature (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | T _A | MIN TYP | MAX | UNIT |
|------------------|---|-------------------------------|-------------------|-----------|-----|-------|
| V _{IO} | Input offset voltage | | 25°C | 1.7 | 7 | mV |
| α _{VIO} | Average temperature coefficient of input offset voltage | | -40°C to 125°C | 5 | | µV/°C |
| | | | 25°C | 15 | 250 | |
| I _{IB} | Input bias current | | -40°C to 125°C | | 400 | nA |
| | | | 25°C | 5 | 50 | nA |
| I _{IO} | Input offset current | | -40°C to 125°C | | 150 | |
| I _O | Output current (sinking) | V ₀ ≤ 1.5 V | 25°C | 5 23 | | mA |
| | | | 25°C | 0.003 | | |
| | Output Leakage Current | | -40°C to 125°C | | 1 | μA |
| V _{ICR} | Common-mode input voltage range | | 25°C | –0.1 to 2 | | V |
| V _{SAT} | Saturation voltage | I _O ≤ 1.5 mA | 25°C | 200 | | mV |
| | | LMV331 | 25°C | 40 | 100 | |
| I _{CC} | Supply current | LMV393 (both comparators) | 25°C | 70 | 140 | μA |
| | | LMV339 (all four comparators) | 25°C | 140 | 200 | |



6.6 Electrical Characteristics, V_{CC+} = 5 V

 V_{CC+} = 5 V, GND = 0 V, at specified free-air temperature (unless otherwise noted)

| 001 | PARAMETER | TEST CONDITIONS | T _A | MIN TYI | P MAX | UNIT |
|------------------|---|-------------------------------|-------------------|-------------|-------|-------|
| | | | 25°C | 1. | 7 7 | |
| V _{IO} | Input offset voltage | | -40°C to 125°C | | 9 | mV |
| α _{VIO} | Average temperature coefficient of input offset voltage | | 25°C | | 5 | µV/°C |
| | | | 25°C | 2 | 5 250 | |
| I _{IB} | Input bias current | | -40°C to 125°C | | 400 | nA |
| | | | 25°C | | 2 50 | |
| I _{IO} | Input offset current | | -40°C to 125°C | | 150 | nA |
| lo | Output current (sinking) | V ₀ ≤ 1.5 V | 25°C | 10 84 | 4 | mA |
| | Output Leakage Current | | 25°C | 0.00 | 3 | |
| | | | -40°C to 125°C | | 1 | μA |
| V _{ICR} | Common-mode input voltage range | | 25°C | –0.1 to 4.1 | 2 | V |
| A _{VD} | Large-signal differential voltage gain | | 25°C | 20 5 | 0 | V/mV |
| | | | 25°C | 20 | 0 400 | |
| V _{SAT} | Saturation voltage | I _O ≤ 4 mA | -40°C to 125°C | | 700 | mV |
| | | | 25°C | 6 | 0 120 | |
| | | LMV331 | -40°C to 125°C | | 150 | |
| | | | 25°C | 10 | 0 200 | |
| I _{CC} | Supply current | LMV393 (both comparators) | -40°C to 125°C | | 250 | μA |
| | | | 25°C | 17 | 0 300 | |
| | | LMV339 (all four comparators) | -40°C to 125°C | | 350 | |

6.7 Switching Characteristics, V_{CC+} = 2.7 V

 $T_A = 25^{\circ}C$, $V_{CC+} = 2.7$ V, $R_L = 5.1$ k Ω , GND = 0 V (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | ТҮР | UNIT |
|---|-----------|--------------------------|------|------|
| 1 Topugation dolay high to low lovel output | | Input overdrive = 10 mV | 1000 | ns |
| ^I PHL | switching | Input overdrive = 100 mV | 350 | 115 |
| | | Input overdrive = 10 mV | 500 | 20 |
| t _{PLH} | switching | Input overdrive = 100 mV | 400 | ns |



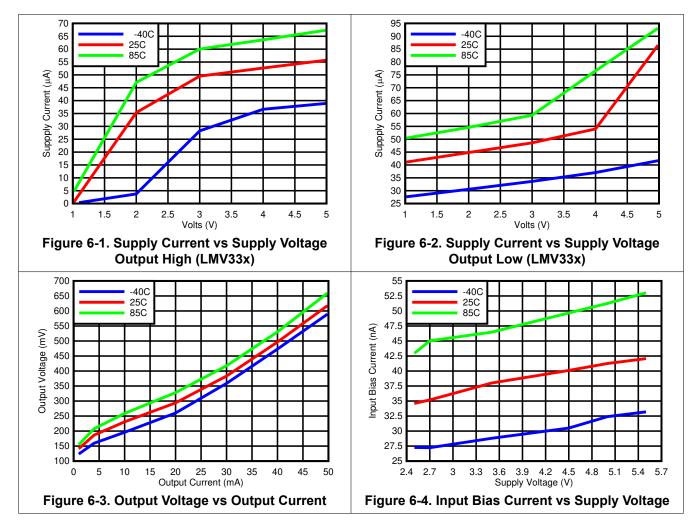
6.8 Switching Characteristics, $V_{CC+} = 5 V$

| | PARAMETER | TEST CONDITIONS | TYP | UNIT |
|--|--|--------------------------|-----|------|
| t _{PHL} Propagation delay high to low switching | Propagation delay high to low level output | Input overdrive = 10 mV | 600 | |
| | switching | Input overdrive = 100 mV | 200 | ns |
| Propagation delay low to hig switching | Propagation delay low to high level output | Input overdrive = 10 mV | 450 | 20 |
| | switching | Input overdrive = 100 mV | 300 | ns |

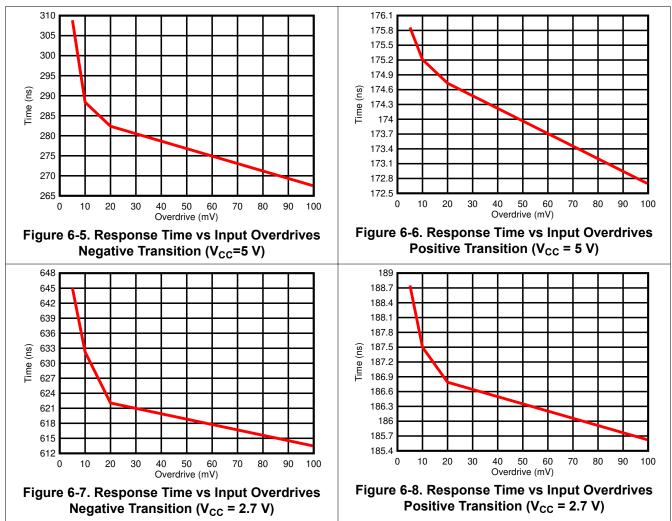
 $T_A = 25^{\circ}C$, $V_{CC+} = 5 V$, $R_L = 5.1 k\Omega$, GND = 0 V (unless otherwise noted)

6.9 Typical Characteristics

Unless otherwise specified, VS = +5V, single supply, TA = 25° C









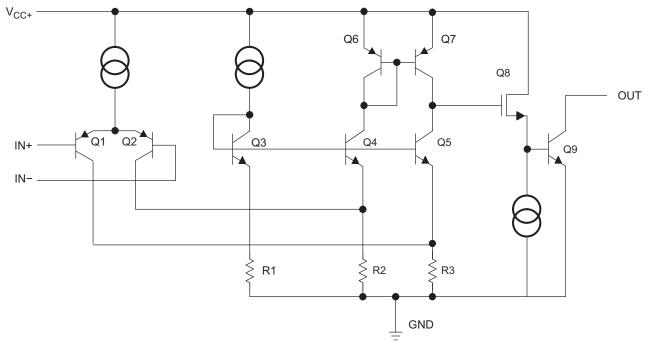
7 Detailed Description

7.1 Overview

The LMV331, LMV393 and LMV339 family of comparators have the ability to operate up to 5 V on the supply pin. This standard device has proven ubiquity and versatility across a wide range of applications. This is due to it's low lq and fast response.

The open-drain output allows the user to configure the output's logic low voltage (V_{OL}) and can be utilized to enable the comparator to be used in AND functionality.

7.2 Functional Block Diagram



7.3 Feature Description

The LMV331, LMV393 and LMV339 consists of a PNP input, whose Vbe creates a limit on the input common mode voltage capability, allowing LMV33x to accurately function from ground to V_{CC} –Vbe(~700mV) differential input. This enables much head room for modern day supplies of 3.3 V and 5.0 V.

The output consists of an open drain NPN (pull-down or low side) transistor. The output NPN will sink current when the positive input voltage is higher than the negative input voltage and the offset voltage. The V_{OL} is resistive and will scale with the output current. Please see Figure 6-3 for V_{OL} values with respect to the output current.

7.4 Device Functional Modes

7.4.1 Voltage Comparison

The LMV33x operates solely as a voltage comparator, comparing the differential voltage between the positive and negative pins and outputs a logic low or high impedance (logic high with pull-up) based on the input differential polarity.



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

LMV331, LMV393, and LMV339 will typically be used to compare a single signal to a reference or two signals against each other. Many users take advantage of the open drain output to drive the comparison logic output to a logic voltage level to an MCU or logic device. The wide supply range and high voltage capability makes LMV331, LMV393, and LMV33 optimal for level shifting to a higher or lower voltage.

8.2 Typical Application

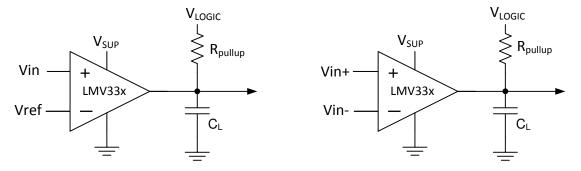


Figure 8-1. Typical Application Schematic

8.2.1 Design Requirements

For this design example, use the parameters listed in Table 8-1 as the input parameters.

| EXAMPLE VALUE | | | | | | | | |
|---------------|--|--|--|--|--|--|--|--|
| 0 V to 4.2 V | | | | | | | | |
| 2.7 V to 5V | | | | | | | | |
| 1 V to 5 V | | | | | | | | |
| 1 µA to 20 mA | | | | | | | | |
| 100 mV | | | | | | | | |
| 2.5 V | | | | | | | | |
| 15 pF | | | | | | | | |
| | | | | | | | | |

Table 8-1. Design Parameters

8.2.2 Detailed Design Procedure

When using LMV331, LMV393, and LMV33 in a general comparator application, determine the following:

- Input Voltage Range
- Minimum Overdrive Voltage
- Output and Drive Current
- Response Time



8.2.2.1 Input Voltage Range

When choosing the input voltage range, the input common mode voltage range (V_{ICR}) must be taken in to account. If operating temperature is above or below 25°C the V_{ICR} can range from 0 V to V_{CC}- 0.7 V. This limits the input voltage range to as high as V_{CC}- 0.7 V and as low as 0 V. Operation outside of this range can yield incorrect comparisons.

Below is a possible list of input voltage situation and their outcomes:

- 1. When both IN- and IN+ are both within the common mode range:
 - a. If IN- is higher than IN+ and the offset voltage, the output is low and the output transistor is sinking current
 - b. If IN- is lower than IN+ and the offset voltage, the output is high impedance and the output transistor is not conducting
- 2. When IN- is higher than common mode and IN+ is within common mode, the output is low and the output transistor is sinking current
- 3. When IN+ is higher than common mode and IN- is within common mode, the output is high impedance and the output transistor is not conducting
- 4. When IN- and IN+ are both higher than common mode, the output is low and the output transistor is sinking current

8.2.2.2 Minimum Overdrive Voltage

Overdrive Voltage is the differential voltage produced between the positive and negative inputs of the comparator over the offset voltage (V_{IO}). In order to make an accurate comparison; the Overdrive Voltage (V_{OD}) should be higher than the input offset voltage (V_{IO}). Overdrive voltage can also determine the response time of the comparator, with the response time decreasing with increasing overdrive. Figure 8-2 show positive and negative response times with respect to overdrive voltage.

8.2.2.3 Output and Drive Current

Output current is determined by the pull-up resistance (Rpullup) and Vlogic voltage, refer to Figure 8-1. The output current will produce a output low voltage (V_{OL}) from the comparator. In which V_{OL} is proportional to the output current. Use Figure 6-3 to determine V_{OL} based on the output current.

The output current can also effect the transient response. More will be explained in the next section.

8.2.2.4 Response Time

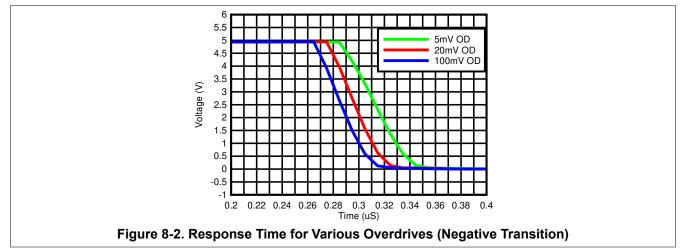
The transient response can be determined by the load capacitance (C_L), load/pull-up resistance (R_{PULLUP}) and equivalent collector-emitter resistance (R_{CE}).

- The positive response time (Tp) is approximately TP ~ RPULLUP × CL
- The negative response time (T_N) is approximately $T_N \sim R_{CE} \times C_L$
 - R_{CE} can be determine by taking the slope of Figure 6-3 in it's linear region at the desired temperature, or by dividing the V_{OL} by I_{out}

8.2.3 Application Curves

The following curves were generated with 5 V on V_{CC} and V_{Logic}, R_{PULLUP} = 5.1 k Ω , and 50 pF scope probe.





9 Power Supply Recommendations

For fast response and comparison applications with noisy or AC inputs, it is recommended to use a bypass capacitor on the supply pin to reject any variation on the supply voltage. This variation cause temporary fluctuations in the comparator's input common mode range and create an inaccurate comparison.

10 Layout

10.1 Layout Guidelines

For accurate comparator applications without hysteresis it is important maintain a stable power supply with minimized noise and glitches, which can affect the high level input common mode voltage range. In order to achieve this, it is best to add a bypass capacitor between the supply voltage and ground. This should be implemented on the positive power supply and negative supply (if available). If a negative supply is not being used, do not put a capacitor between the IC's GND pin and system ground.

10.2 Layout Example

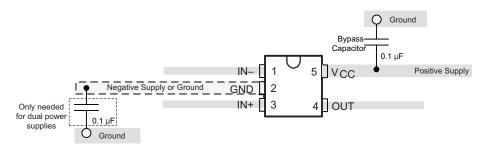


Figure 10-1. LMV331 Layout Example





11 Device and Documentation Support

11.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

| PARTS | PRODUCT FOLDER | PRODUCT FOLDER SAMPLE & BUY | | TOOLS & SOFTWARE | SUPPORT & COMMUNITY | | | | | |
|--------|----------------|-----------------------------|------------|---------------------|---------------------|--|--|--|--|--|
| LMV331 | Click here | Click here | Click here | Click here | Click here | | | | | |
| LMV393 | Click here | Click here | Click here | Click here | Click here | | | | | |
| LMV339 | Click here | Click here | Click here | Click here | Click here | | | | | |

Table 11-1. Related Links

11.2 Trademarks

All other trademarks are the property of their respective owners.

11.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.4 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| LMV331IDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R1IF, R1IK) | Samples |
| LMV331IDBVRE4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R1IF, R1IK) | Samples |
| LMV331IDBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R1IF, R1IK) | Samples |
| LMV331IDBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R1IF, R1IK) | Samples |
| LMV331IDBVTG4 | ACTIVE | SOT-23 | DBV | 5 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R1IF, R1IK) | Samples |
| LMV331IDCKR | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | (R2F, R2K, R2R) | Samples |
| LMV331IDCKRE4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R2F, R2K, R2R) | Samples |
| LMV331IDCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R2F, R2K, R2R) | Samples |
| LMV331IDCKT | ACTIVE | SC70 | DCK | 5 | 250 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | (R2C, R2F, R2R) | Samples |
| LMV331IDCKTE4 | ACTIVE | SC70 | DCK | 5 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R2C, R2F, R2R) | Samples |
| LMV331IDCKTG4 | ACTIVE | SC70 | DCK | 5 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R2C, R2F, R2R) | Samples |
| LMV339ID | ACTIVE | SOIC | D | 14 | 50 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | LMV3391 | Samples |
| LMV339IDR | ACTIVE | SOIC | D | 14 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | LMV3391 | Samples |
| LMV339IPW | ACTIVE | TSSOP | PW | 14 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV339I | Samples |
| LMV339IPWR | ACTIVE | TSSOP | PW | 14 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV339I | Samples |
| LMV339IPWRG4 | ACTIVE | TSSOP | PW | 14 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV339I | Samples |
| LMV339IRUCR | ACTIVE | QFN | RUC | 14 | 3000 | RoHS & Green | NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | (RT, RTR) | Samples |
| LMV393ID | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |
| LMV393IDDUR | ACTIVE | VSSOP | DDU | 8 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | RABR | Samples |
| LMV393IDGKR | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | (R9B, R9Q, R9R) | Samples |

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-----------------|---------|
| | (1) | | Drawing | | QLY | (2) | (6) | (3) | | (4/5) | |
| LMV393IDGKRG4 | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | (R9B, R9Q, R9R) | Samples |
| LMV393IDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |
| LMV393IDRG4 | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |
| LMV393IPW | ACTIVE | TSSOP | PW | 8 | 150 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |
| LMV393IPWG4 | ACTIVE | TSSOP | PW | 8 | 150 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |
| LMV393IPWR | ACTIVE | TSSOP | PW | 8 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |
| LMV393IPWRG4 | ACTIVE | TSSOP | PW | 8 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | MV393I | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF LMV331, LMV393 :

• Automotive : LMV331-Q1, LMV393-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

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Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| Device | Package Type | Package Drawing | | SPQ | Reel Diameter | Reel Width | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|-----------------|--------------------|----|------|------------------|---------------|------------|------------|------------|------------|-----------|------------------|
| | , | Ŭ | | | (mm) | W1 (mm) | · · / | , , | . , | , , | , | |
| LMV331IDBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| LMV331IDBVT | SOT-23 | DBV | 5 | 250 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| LMV331IDCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| LMV331IDCKT | SC70 | DCK | 5 | 250 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| LMV331IDCKT | SC70 | DCK | 5 | 250 | 180.0 | 9.2 | 2.3 | 2.55 | 1.2 | 4.0 | 8.0 | Q3 |
| LMV339IDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| LMV339IPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| LMV339IRUCR | QFN | RUC | 14 | 3000 | 180.0 | 8.4 | 2.3 | 2.3 | 0.55 | 4.0 | 8.0 | Q2 |
| LMV393IDDUR | VSSOP | DDU | 8 | 3000 | 180.0 | 8.4 | 2.25 | 3.35 | 1.05 | 4.0 | 8.0 | Q3 |
| LMV393IDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LMV393IDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| LMV393IDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.3 | 1.3 | 8.0 | 12.0 | Q1 |
| LMV393IDR | SOIC | D | 8 | 2500 | 330.0 | 12.8 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LMV393IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LMV393IDRG4 | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| LMV393IPWR | TSSOP | PW | 8 | 2000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LMV331IDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| LMV331IDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |
| LMV331IDCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| LMV331IDCKT | SC70 | DCK | 5 | 250 | 180.0 | 180.0 | 18.0 |
| LMV331IDCKT | SC70 | DCK | 5 | 250 | 205.0 | 200.0 | 33.0 |
| LMV339IDR | SOIC | D | 14 | 2500 | 356.0 | 356.0 | 35.0 |
| LMV339IPWR | TSSOP | PW | 14 | 2000 | 356.0 | 356.0 | 35.0 |
| LMV339IRUCR | QFN | RUC | 14 | 3000 | 202.0 | 201.0 | 28.0 |
| LMV393IDDUR | VSSOP | DDU | 8 | 3000 | 202.0 | 201.0 | 28.0 |
| LMV393IDGKR | VSSOP | DGK | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| LMV393IDGKR | VSSOP | DGK | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| LMV393IDGKR | VSSOP | DGK | 8 | 2500 | 370.0 | 355.0 | 55.0 |
| LMV393IDR | SOIC | D | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| LMV393IDR | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LMV393IDRG4 | SOIC | D | 8 | 2500 | 340.5 | 336.1 | 25.0 |
| LMV393IPWR | TSSOP | PW | 8 | 2000 | 356.0 | 356.0 | 35.0 |

TEXAS INSTRUMENTS

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3-Jun-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LMV339ID | D | SOIC | 14 | 50 | 506.6 | 8 | 3940 | 4.32 |
| LMV339IPW | PW | TSSOP | 14 | 90 | 530 | 10.2 | 3600 | 3.5 |
| LMV393ID | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| LMV393IPW | PW | TSSOP | 8 | 150 | 530 | 10.2 | 3600 | 3.5 |
| LMV393IPWG4 | PW | TSSOP | 8 | 150 | 530 | 10.2 | 3600 | 3.5 |

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



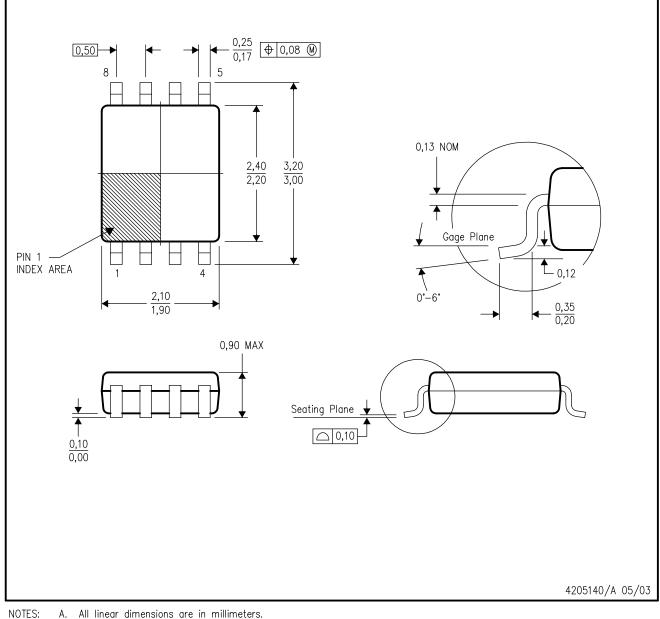
NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DDU (R-PDSO-G8)

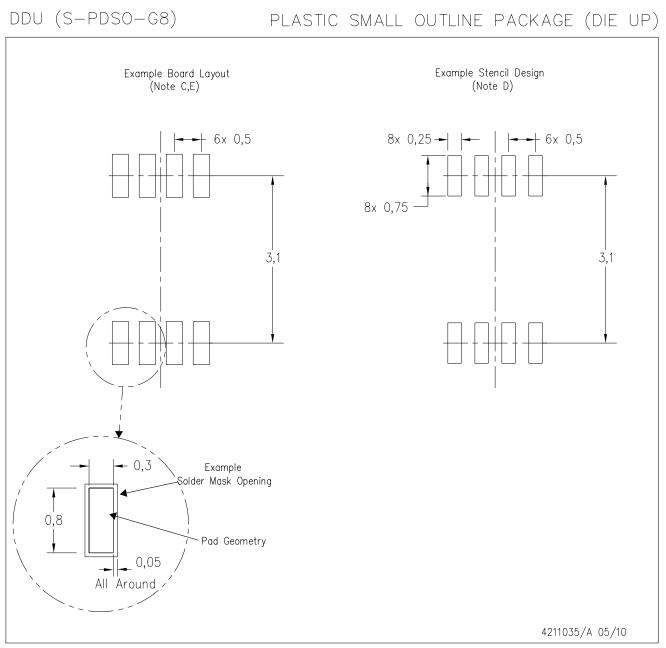
PLASTIC SMALL-OUTLINE PACKAGE



Α. All linear dimensions are in millimeters.

- Β. This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion. C.
- D. Falls within JEDEC MO-187 variation CA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.



DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW0008A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



PW0008A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0008A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



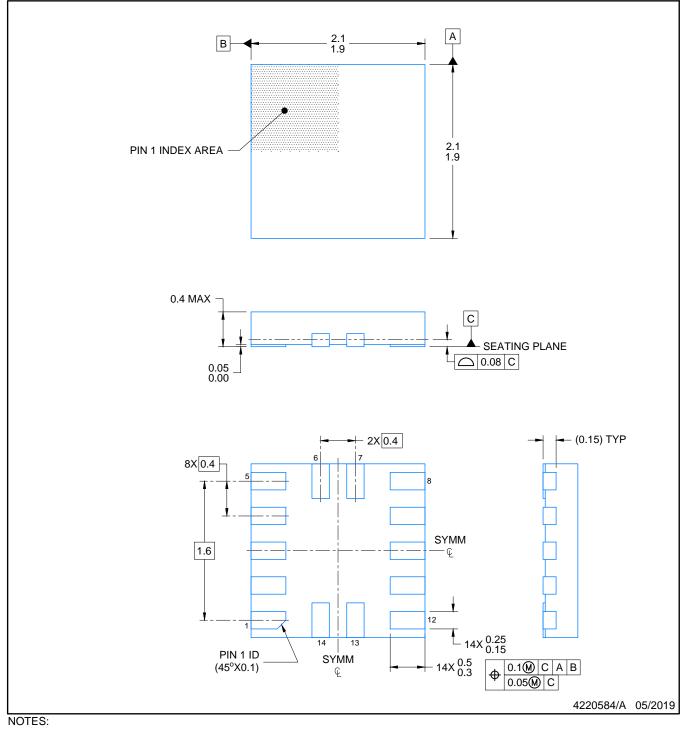
^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

RUC0014A

PACKAGE OUTLINE

X2QFN - 0.4 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

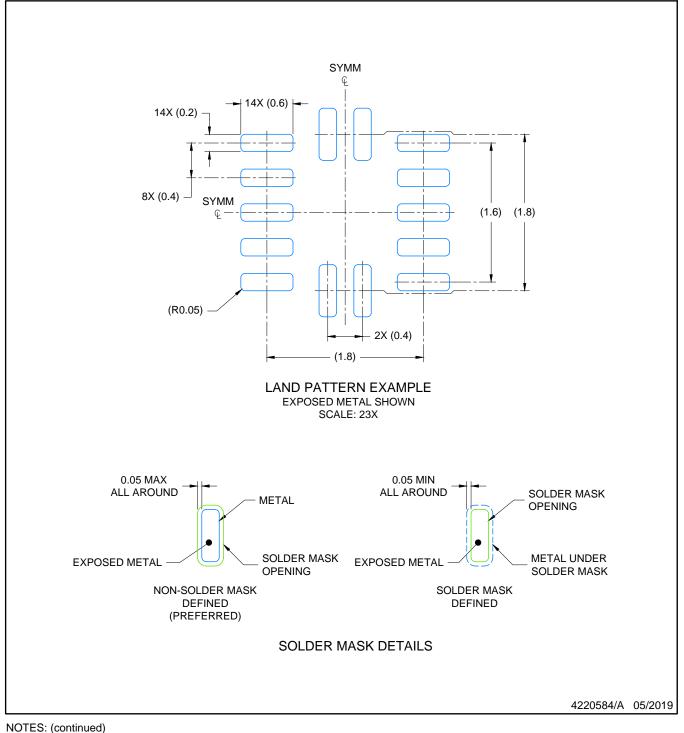


RUC0014A

EXAMPLE BOARD LAYOUT

X2QFN - 0.4 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

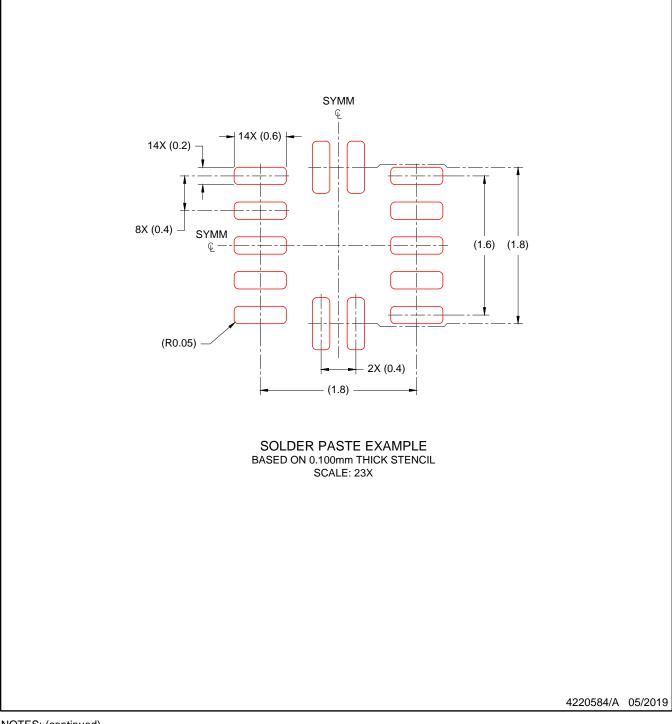


RUC0014A

EXAMPLE STENCIL DESIGN

X2QFN - 0.4 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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